Property of Lite-On Only

FEATURES

- *0.52INCH (13.2mm) DIGIT HEIGHT
- *CONTINUOUS UNIFORM SEGMENTS
- ***LOW POWER REQUIREMENT**
- *EXCELLENT CHARACTERS APPEARANCE
- *HIGH BRIGHTNESS & HIGH CONTRAST
- *WIDE VIEWING ANGLE
- *** SOLID STATE RELIABILITY**
- *CATEGORIZED FOR LUMINOUS INTENSITY

DESCRIPTION

The LTD-5250E is a 0.52inch (13.2mm) digit height dual digit seven-segment display. The device unilizes red orange LED chips, which are made from GaAsP on a transparent GaP substrate, and has a gray face and white segments.

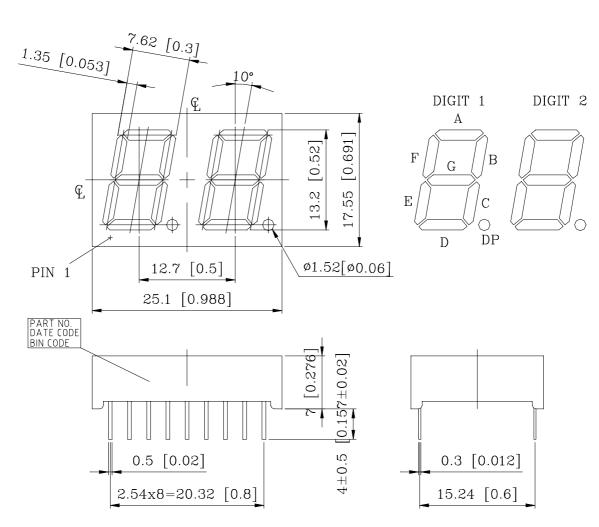
DEVICE

PART NO.	DESCRIPTION			
RED ORANGE	COMMON ANODE			
LTD-5250E	RT. HAND DECIMAL			

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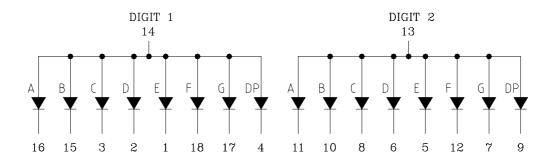
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PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are \pm 0.25 mm unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



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PIN CONNECTION

No.	CONNECTION					
1	CATHODE E (DIGIT 1)					
2	CATHODE D (DIGIT 1)					
3	CATHODE C (DIGIT 1)					
4	CATHODE DP (DIGIT 1)					
5	CATHODE E (DIGIT 2)					
6	CATHODE D (DIGIT 2)					
7	CATHODE G (DIGIT 2)					
8	CATHODE C (DIGIT 2)					
9	CATHODE DP (DIGIT 2)					
10	CATHODE B (DIGIT 2)					
11	CATHODE A (DIGIT 2)					
12	CATHODE F (DIGIT 2)					
13	COMMON ANODE (DIGIT 2)					
14	COMMON ANODE (DIGIT 1)					
15	CATHODE B (DIGIT 1)					
16	CATHODE A (DIGIT 1)					
17	CATHODE G (DIGIT 1)					
18	CATHODE F (DIGIT 1)					

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ABSOLUTE MAXIMUM RATING AT T_A=25°C

The second secon						
PARAMETER	MAXIMUM RATING	UNIT				
Power Dissipation Per Chip	75	mW				
Peak Forward Current Per Chip	100	mA				
(1/10 Duty Cycle, 0.1ms Pulse Width)	100					
Continuous Forward Current Per Chip	25	mA				
Derating Linear From 25°C Per Chip	0.33	mA/°C				
Reverse Voltage Per Chip	5	V				
Operating Temperature Range	-35°C to +85°C					
Storage Temperature Range	rge Temperature Range -35°C to +85°C					
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane						

TRICAL / OPTICAL CHARACTERISTICS AT $T_A=25^{\circ}C$

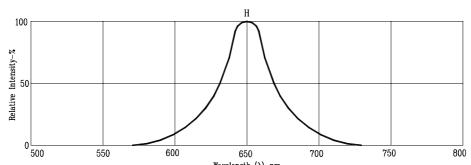
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	Iv	800	2200		μcd	I _F =10mA
Peak Emission Wavelength	λр		630		nm	I _F =20mA
Spectral Line Half-Width	Δλ		40		nm	I _F =20mA
Dominant Wavelength	λd		621		nm	I _F =20mA
Forward Voltage Per Chip	V_{F}		2.0	2.6	V	I _F =20mA
Reverse Current Per Chip	IR			100	μΑ	$V_R=5V$
Luminous Intensity Matching Ratio	Iv-m			2:1		I _F =10mA

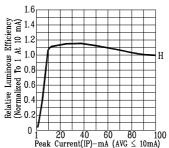
Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

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TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

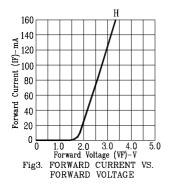
(25°C Ambient Temperature Unless Otherwise Noted)

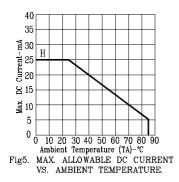




0 1 20 40 60 80 100
Peak Current(IP)-mA (AVG \(\) 10mA)

Fig2. RELATIVE LUMINOUS EFFICIENCY
(LUMINOUS INTENSITY PER UNIT
CURRENT) VS. PEAK CURRENT
(REFRESH RATE 1KHZ)





Relative Luminous Intensity

Relative Luminous Intensity

Relative Luminous Intensity

Relative Luminous Intensity

H

H

H

H

Forward Current (IF)—mA

Fig4. RELATIVE LUMINOUS INTENSITY
VS. FORWARD CURRENT

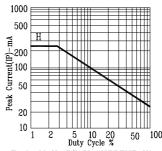


Fig6. MAX PEAK CURRENT VS.
DUTY CYCLE %
(REFRESH RATE 1KHz)

NOTE: H=HI.EFF.-RED

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